Electrical Characteristics (T_J=25 unless otherwise noted)

Parameter	Symbol	Conditions		Min	Typ	Max	Units
Static Parameter							
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}= 0V, I_D=250		60			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=60V,V_{GS}=0V	T_J=25			1	
			T_J=55			5	
Gate-Body Leakage Current	I_{GSS}	V_{GS}= ± 20V, V_{DS}=0V				± 100	nA

■ Typical Performance Characteristics

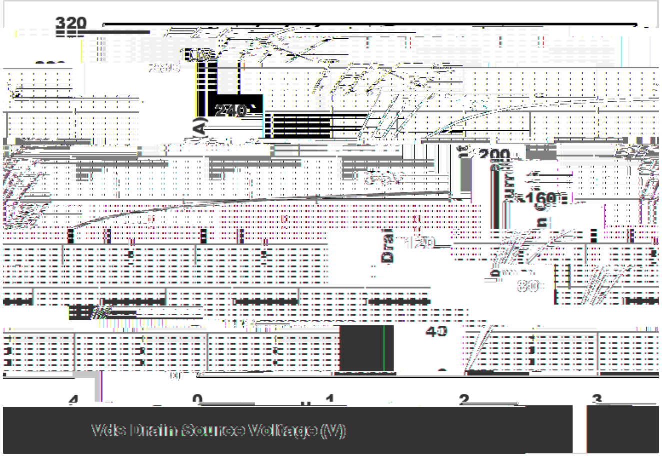

Figure1. Output Characteristics

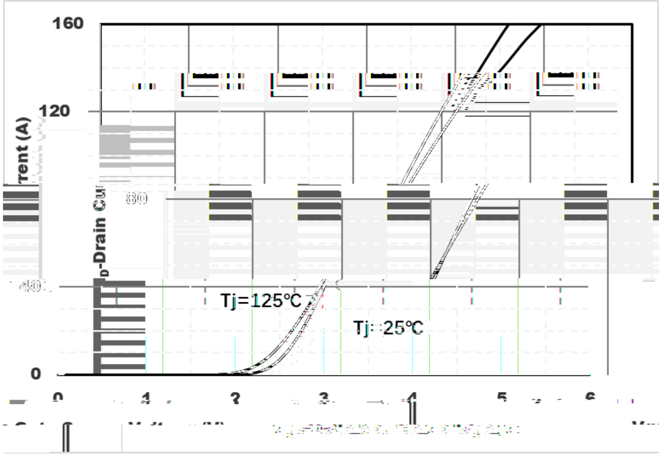

Figure2. Transfer Characteristics

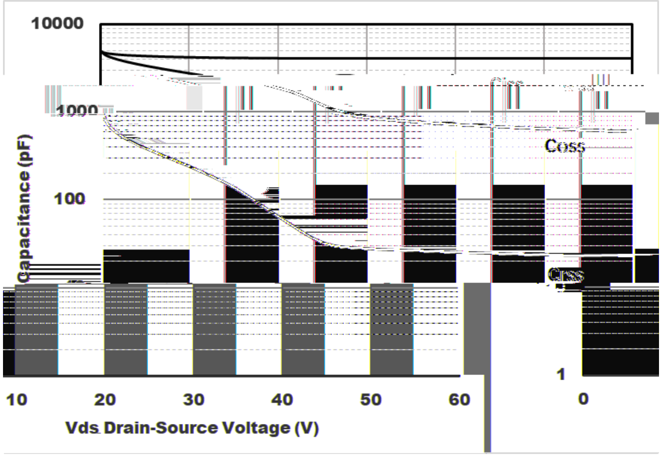

Figure3. Capacitance Characteristics

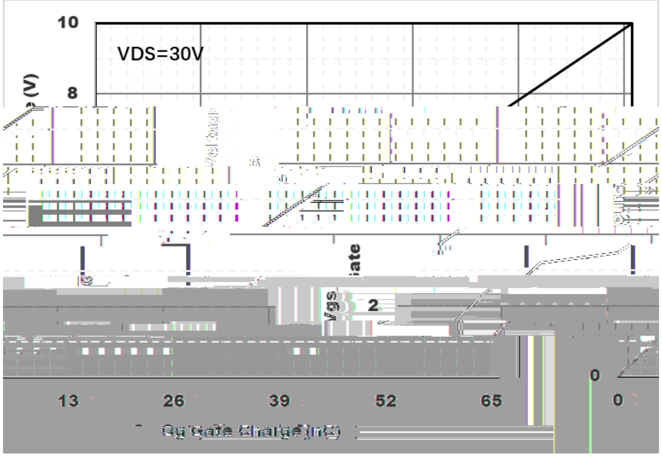

Figure4. Gate Charge

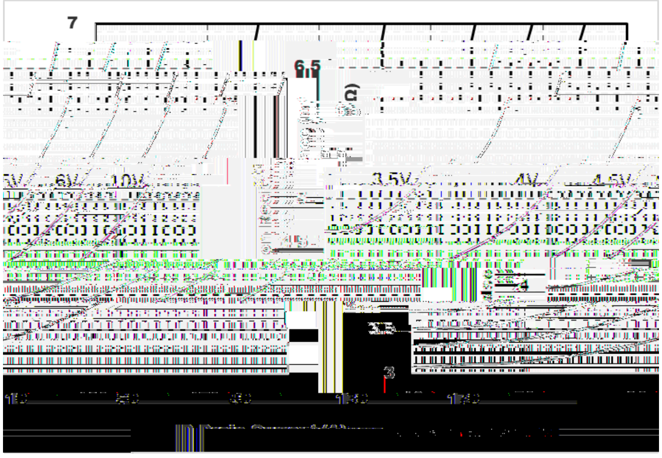

Figure5. Drain-Source on Resistance

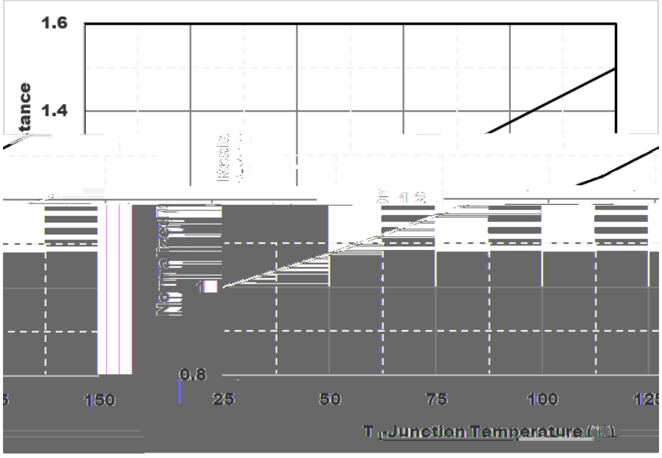

Figure6. Normalized On-Resistance

Disclaimer

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